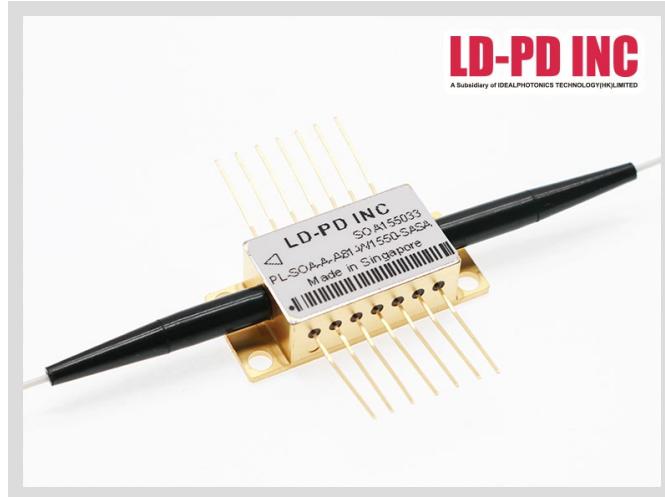


# C-Band Semiconductor Optical Amplifier, Non-linear



## Description:

The PL-SOA-A-A81-W1550-SASA is a polarization-insensitive optical amplifier with advanced epitaxial wafer growth and opto-electronic packaging techniques that enable a high output saturation power, low noise figure, and large gain across a broad spectral bandwidth.

## Features:

- Wide Optical Bandwidth
- High Output Power
- Low Polarization Sensitivity
- MQW or Bulk Structure

## Applications:

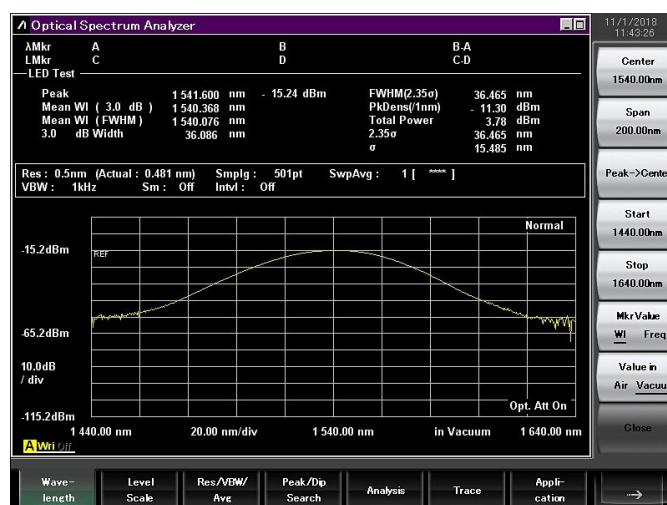
- Booster Amplifier
- Telecom and Datacom
- Loss Compensation

## Laser Specifications:

Electrical/Optical Characteristics(T<sub>sub</sub>=25°C, CW bias unless stated otherwise)

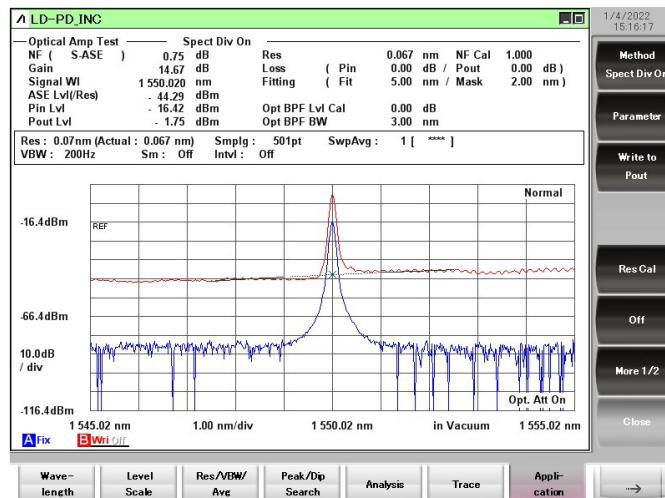
| Item #   | Symbol           | PL-SOA-A-A81-W1550-SASA |         |         |
|--|------------------|-------------------------|---------|---------|
|  |                  | Min                     | Typical | Max     |
| Operating Current                                    | I <sub>OP</sub>  | -                       | 450 mA  | 500 mA  |
| Operating Wavelength Range                           |                  | 1528 nm                 | -       | 1562 nm |
| Center Wavelength                                    | λ <sub>C</sub>   | -                       | 1550    | -       |
| Saturation Output Power <sup>b</sup> (@ -3 dB)       | P <sub>SAT</sub> | 12 dBm                  | 14 dBm  | -       |
| Small Signal Gain (Over C-Band @ Pin = -20 dBm)      | G                | 10 dB                   | 13 dB   | -       |
| Gain Flatness (Over C-Band @ Pin = -20 dBm)          | ΔG               | -                       | 5 dB    | 7 dB    |
| Gain Ripple (p-p) @ I <sub>OP</sub> , λ <sub>C</sub> | δG               | -                       | 0.1 dB  | 0.5 dB  |
| Polarization Dependent Gain                          | P <sub>DG</sub>  | -                       | 1.0 dB  | 1.8 dB  |
| Noise Figure   | NF               | -                       | 8 dB    | 9.5 dB  |
| Forward Voltage                                      | V <sub>F</sub>   | -                       | 1.6 V   | 1.8 V   |
| Chip Length  | -                | -                       | 1.5 mm  | -       |
| Waveguide Refractive Index                           | -                | -                       | 3.2     | -       |
| TEC Operation (Typical/Max @ TCASE = 25/70 °C)       |                  |                         |         |         |
| TEC Current  | I <sub>TEC</sub> | -                       | 0.23 A  | 1.5 A   |
| TEC Voltage  | V <sub>TEC</sub> | -                       | 0.5 V   | 4.0 V   |
| Thermistor Resistance                                | R <sub>TH</sub>  | -                       | 10 kΩ   | -       |

## ASE Spectrum:

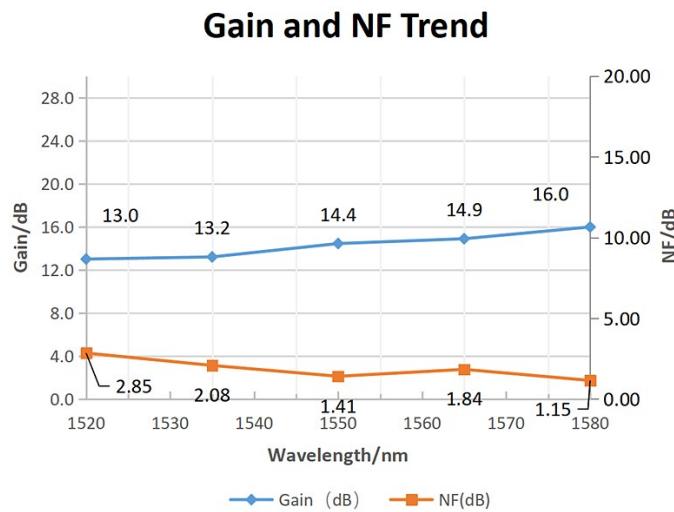


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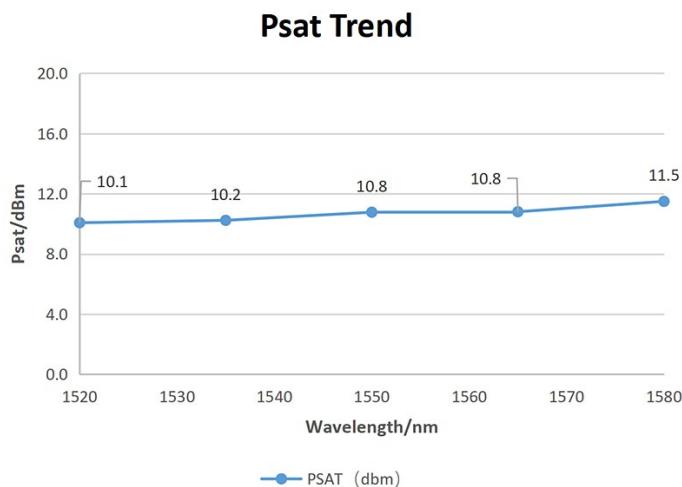
## SOA Power amplification comparison(Pin = 0dBm, I = 450 mA):



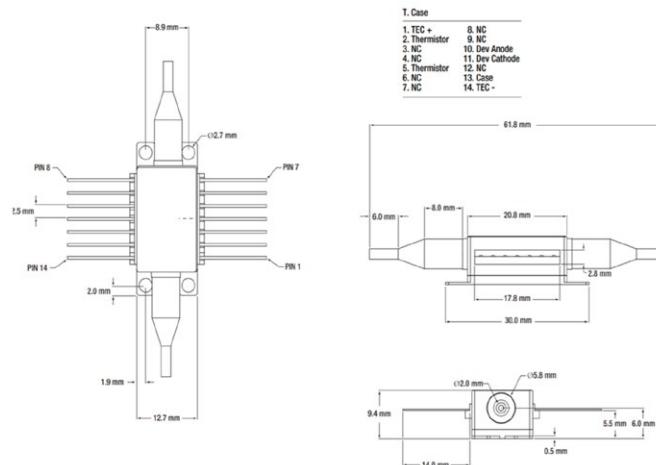
## Gain and NF Trend:



## Psat Trend:



## Dimensions and Pin definitions:



| NO. | Function   | NO. | Function        |
|-----|------------|-----|-----------------|
| 1   | TEC (+)    | 8   | N/C             |
| 2   | Thermistor | 9   | N/C             |
| 3   | NC         | 10  | Dev Anode (+)   |
| 4   | NC         | 11  | Dev Cathode (-) |
| 5   | Thermistor | 12  | N/C             |
| 6   | N/C        | 13  | Case            |
| 7   | N/C        | 14  | TEC (-)         |

## Ordering Info:

PL-SOA-☆-A8▽-W□□□□-XX

☆ : Output Power

A: 5dbm

B: 10dbm

▽: Bandwidth

1: 60-70nm

2: 30-40nm

□□□□: Wavelength

680: 680nm

850: 850nm

\*\*\*\*\*

1550: 1550nm

1600: 1600nm

XX: Fiber and Connector Type

SASA=(SMF-28E+ FC/APC)+(SMF-28E+ FC/APC)

SPSP=(SMF-28E+ FC/PC)+(SMF-28E+ FC/PC)

PAPA=(PM Fiber+ FC/APC)+(PM Fiber+ FC/APC)

PPPP=(PM Fiber+ FC/PC)+(PM Fiber+ FC/PC)

PAPA=(PM Fiber+ FC/APC)+(PM Fiber+ FC/APC)